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# FSQ100 Green Mode Fairchild Power Switch (FPS™)

# Features

- Internal Avalanche-Rugged SenseFET
- Precision Fixed Operating Frequency: 67KHz
- Burst-Mode Operation

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- Internal Startup Circuit
- Pulse-by-Pulse Current Limiting
- Over-Voltage Protection (OVP)
- Overload Protection (OLP)
- Internal Thermal Shutdown Function (TSD)
- Auto-Restart Mode
- Under-Voltage Lockout (UVLO) with Hysteresis
- Built-in Soft-Start
- Secondary-Side Regulation

# Applications

- Charger & Adapter for Mobile Phone, PDA, MP3
- Auxiliary Power for White Goods, PC, C-TV, Monitor

# **Related Application Notes**

- AN-4137 Design Guidelines for Off-line Flyback Converters using FPS™
- AN-4141 Troubleshooting and Design Tips for Fairchild Power Switch (FPS™) Flyback Applications
- AN-4147 Design Guidelines for RCD Snubber of <u>Flyback</u>
- AN-4134 Design Guidelines for Off-line Forward Converters using FPS™
- <u>AN-4138</u> Design Considerations for Battery Charger Using Green Mode Fairchild Power Switch (FPS™)

# Description

The FSQ100 consists of an integrated Pulse Width Modulator (PWM) and SenseFET, specifically designed for high-performance, off-line, Switch-Mode Power Supplies (SMPS) with minimal external components. This device is an integrated high-voltage power switching regulator that combines a VDMOS SenseFET with a voltage mode PWM control block. The integrated PWM controller features include a fixed oscillator, Under-Voltage Lockout (UVLO) protection, Leading Edge Blanking (LEB), an optimized gate turn-on/turn-off driver, Thermal Shutdown (TSD) protection, and temperature-compensated precision-current sources for loop compensation and fault protection circuitry.

When compared to a discrete MOSFET and controller or RCC solution, the FSQ100 device reduces total component count and design size and weight, while increasing efficiency, productivity, and system reliability. This device provides a basic platform well suited for cost-effective flyback converters.



### **Ordering Information**

Product Number	Package	Marking Code	BV <sub>DSS</sub>	f <sub>osc</sub>	R <sub>DS(ON)</sub>
FSQ100	8-DIP	Q100	650V	67KHz	16Ω

FPS<sup>™</sup> is a trademark of Fairchild Semiconductor Corporation.

# Typical Application



## Table 1. Output Power Table

Product	Open Frame <sup>(1)</sup>		
	230V <sub>AC</sub> ±15% <sup>(2)</sup>	85~265V <sub>AC</sub>	
FSQ100	13W	8W	

Notes:

- 1. Maximum practical continuous power in an open-frame design with sufficient drain pattern as a heat sinker, at 50°C ambient.
- 2. 230V\_{AC} or 100/115V\_{AC} with doubler.

# Internal Block Diagram



FSQ100 — Green Mode Fairchild Power Switch (FPS<sup>TM</sup>)

**Pin Assignments** 



Figure 3. Pin Configuration (Top View)

# **Pin Definitions**

Pin #	Name	Description		
1	GND	Ground. SenseFET source terminal on primary-side and internal control ground.		
2	V <sub>CC</sub>	<b>Positive Supply Voltage Input</b> . Although connected to an auxiliary transformer winding, current is supplied from pin 5 ( $V_{STR}$ ) via an internal switch during startup (see Figure 2). When $V_{CC}$ reaches the UVLO upper threshold (9V), the internal startup switch opens and device power is supplied via the auxiliary transformer winding.		
3	$V_{FB}$	<b>Feedback</b> . Inverting input to the PWM comparator with its normal input level lies between 0.5V and 2.5V. It has a 0.4mA current source connected internally, while a capacitor and opto-coupler are typically connected externally. A feedback voltage of 4.5V triggers overload protection (OLP). There is a time delay while charging external capacitor C <sub>fb</sub> from 3V to 4.5V using an internal 5 $\mu$ A current source. This time delay prevents false triggering under transient conditions, but still allows the protection mechanism to operate in true overload conditions.		
4	NC	No Connection.		
5	$V_{\text{STR}}$	<b>Startup</b> . This pin connects directly to the rectified AC line voltage source. At startup, the internal switch supplies internal bias and charges an external storage capacitor placed between the $V_{CC}$ pin and ground. Once the $V_{CC}$ reaches 9V, the internal switch stops charging the capacitor.		
6,7,8	Drain	<b>SenseFET Drain</b> . The drain pins are designed to connect directly to the primary lead of the transformer and are capable of switching a maximum of 650V. Minimizing the length of the trace connecting these pins to the transformer decreases leakage inductance.		

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A = 25^{\circ}C$ , unless otherwise specified.

Symbol	Parameter	Value	Unit
V <sub>DRAIN</sub>	Drain Pin Voltage	650	V
V <sub>STR</sub>	VSTR Pin Voltage	650	V
V <sub>DG</sub>	Drain-Gate Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
V <sub>cc</sub>	Supply Voltage	20	V
V <sub>FB</sub>	Feedback Voltage Range	-0.3 to V <sub>STOP</sub>	V
PD	Total Power Dissipation	1.40	W
TJ	Operating Junction Temperature	Internally limited	°C
T <sub>A</sub>	Operating Ambient Temperature	-25 to +85	°C
T <sub>STG</sub>	Storage Temperature	-55 to +150	°C

Notes:

1. Repetitive rating: Pulse width is limited by maximum junction temperature.

2. L = 24mH, starting  $T_J$  = 25°C.

# **Thermal Impedance**

T<sub>A</sub> = 25°C, unless otherwise specified. All items are tested with the JEDEC standards JESD 51-2 and 51-10 (DIP).

Symbol	Parameter	Value	Unit
θ <sub>JA</sub>	Junction-to-Ambient Thermal Impedance <sup>(3)</sup>	88.84	°C/W
$\theta_{JC}$	Junction-to-Case Thermal Impedance <sup>(4)</sup>	13.94	°C/W

Notes:

Free-standing with no heatsink; without copper clad. Measurement condition; just before junction temperature T<sub>J</sub> enters into OTP.

4. Measured on the DRAIN pin close to plastic interface.

# **Electrical Characteristics**

 $T_A$  = 25°C, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SenseFET S	Section				11	
1	Zero Cato Valtago Drain Current	V <sub>DS</sub> =650V, V <sub>GS</sub> =0V			25	μA
I <sub>DSS</sub>	Zero-Gate-Voltage Drain Current	$V_{DS}$ =520V, $V_{GS}$ =0V, $T_{C}$ =125°C			200	
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance <sup>(5)</sup>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A		16	22	Ω
<b>g</b> <sub>fs</sub>	Forward Trans-Conductance	V <sub>DS</sub> =50V, I <sub>D</sub> =0.5A	1.0	1.3		S
CISS	Input Capacitance			162		pF
Coss	Output Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		18		
C <sub>RSS</sub>	Reverse Transfer Capacitance			3.8		
Control Sec	tion					
f <sub>OSC</sub>	Switching Frequency		61	67	73	kHz
$\Delta f_{OSC}$	Switching Frequency Variation <sup>(6)</sup>	-25°C ≤ T <sub>A</sub> ≤ 85°C		±5	±10	%
D <sub>MAX</sub>	Maximum Duty Cycle		60	67	74	%
V <sub>START</sub>		V <sub>FB</sub> =GND	8	9	10	V
V <sub>STOP</sub>	UVLO Threshold Voltage	V <sub>FB</sub> =GND	6	7	8	V
I <sub>FB</sub>	Feedback Source Current	$0V \le V_{FB} \le 3V$	0.35	0.40	0.45	mA
t <sub>s/s</sub>	Internal Soft Start Time		10	15	20	ms
Burst Mode	Section			•		
V <sub>BURH</sub>		T -25%0	0.6	0.7	0.8	V
V <sub>BURL</sub>	Burst Mode Voltage	T <sub>J</sub> =25°C	0.45	0.55	0.65	V
V <sub>BUR(HYS)</sub>		Hysteresis		150		mV
Protection S	Section		•	•		
I <sub>LIM</sub>	Peak Current Limit		0.475	0.550	0.650	Α
$T_{SD}$	Thermal Shutdown Temperature <sup>(7)</sup>		125	145		°C
$V_{SD}$	Shutdown Feedback Voltage		4.0	4.5	5.0	V
V <sub>OVP</sub>	Over-Voltage Protection		20			V
I <sub>DELAY</sub>	Shutdown Delay Current	$3V \le V_{FB} \le V_{SD}$	4	5	6	μA
Total Device	Section		•	•		
I <sub>OP</sub>	Operating Supply Current <sup>(8)</sup>	V <sub>CC</sub> ≤ 16V		1.5	3.0	mA
I <sub>CH</sub>	Startup Charging Current	V <sub>CC</sub> =0V , V <sub>STR</sub> =50V	450	550	650	μA
	•			•	•	

Notes:

5. Pulse test: Pulse width  $\leq$  300µs, duty  $\leq$  2%.

6. These parameters, although guaranteed, are tested in EDS (wafer test) process.

7. These parameters, although guaranteed, are not 100% tested in production.

8. Control part only.



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### **Functional Description**

**1. Startup**: At startup, the internal high-voltage current source supplies the internal bias and charges the external V<sub>CC</sub> capacitor, as shown in Figure 14. When V<sub>CC</sub> reaches 9V, the device starts switching and the internal high-voltage current source stops charging the capacitor. The device is in normal operation provided V<sub>CC</sub> does not drop below 7V. After startup, the bias is supplied from the auxiliary transformer winding.



Figure 14. Internal Startup Circuit

Calculating the V<sub>CC</sub> capacitor is an important step to design with the FSQ100. At initial startup, the maximum value of start operating current I<sub>START</sub> is about 100µA, which supplies current to UVLO and V<sub>REF</sub> blocks. The charging current I<sub>VCC</sub> of the V<sub>CC</sub> capacitor is equal to I<sub>STR</sub> – 100µA. After V<sub>CC</sub> reaches the UVLO start voltage, only the bias winding supplies V<sub>CC</sub> current to the device. When the bias winding voltage is not sufficient, the V<sub>CC</sub> level decreases to the UVLO stop voltage and the internal current source is activated again to charge the V<sub>CC</sub> capacitor. To prevent this V<sub>CC</sub> fluctuation (charging/discharging), the V<sub>CC</sub> capacitor should be chosen to have a value between 10µF and 47µF.



Figure 15. Charging V<sub>CC</sub> Capacitor through Vstr

**2. Feedback Control**: The FSQ100 is a voltage mode controlled device, as shown in Figure 16. Usually, an opto-coupler and shunt regulator, like KA431 are used to implement the feedback network. The feedback voltage is compared with an internally generated sawtooth waveform. This directly controls the duty cycle.

When the shunt regulator reference pin voltage exceeds the internal reference voltage of 2.5V, the opto-coupler LED current increases, the feedback voltage  $V_{FB}$  is pulled down, and it reduces the duty cycle. This happens when the input voltage increases or the output load decreases.



Figure 16. PWM and Feedback Circuit

**3. Leading Edge Blanking (LEB)**: At the instant the internal SenseFET is turned on, the primary-side capacitance and secondary-side rectifier diode reverse recovery typically causes a high-current spike through the SenseFET. Excessive voltage across the  $R_{SENSE}$  resistor lead to incorrect pulse-by-pulse current limit protection. To avoid this, a leading edge blanking (LEB) circuit disables pulse-by-pulse current-limit protection block for a fixed time ( $t_{LEB}$ ) after the SenseFET turns on.

4. Protection Circuit: The FSQ100 has protective functions, such as overload protection (OLP), over voltage protection (OVP), under-voltage lockout (UVLO), and thermal shutdown (TSD). Because these protection circuits are fully integrated inside the IC without external components, reliability is improved without increasing costs. Once a fault condition occurs, switching is terminated and the SenseFET remains off. This causes  $V_{CC}$  to fall. When  $V_{CC}$  reaches the UVLO stop voltage  $V_{\text{STOP}}$  (7V), the protection is reset and the internal highvoltage current source charges the V<sub>CC</sub> capacitor via the  $V_{STR}$  pin. When  $V_{CC}$  reaches the UVLO start voltage V<sub>START</sub> (9V), the device resumes normal operation. In this manner, the auto-restart can alternately enable and disable the switching of the power SenseFET until the fault condition is eliminated.



4.1 Overload Protection (OLP): Overload is defined as the load current exceeding a pre-set level due to an unexpected event. In this situation, the protection circuit should be activated to protect the SMPS. However, even when the SMPS is operating normally, the over load protection (OLP) circuit can be activated during the load transition. To avoid this undesired operation, the OLP circuit is designed to be activated after a specified time to determine whether it is a transient situation or a true overload situation. If the output consumes more than the maximum power determined by ILIM, the output voltage (V<sub>0</sub>) decreases below its rating voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor current, thus increasing the feedback voltage ( $V_{FB}$ ). If  $V_{FB}$ exceeds 3V, the feedback input diode is blocked and the 5µA current source (I<sub>DELAY</sub>) starts to charge C<sub>FB</sub> slowly up to  $V_{CC}$ . In this condition,  $V_{FB}$  increases until it reaches 4.5V, when the switching operation is terminated, as shown in Figure 18. The shutdown delay time is the time required to charge  $C_{FB}$  from 3V to 4.5V with a 5 $\mu A$ current source.



Figure 18. Overload Protection (OLP)

**4.2 Thermal Shutdown (TSD)**: The SenseFET and the control IC are integrated, making it easier for the control IC to detect the temperature of the SenseFET. When the temperature exceeds approximately 145°C, thermal shutdown is activated.

**5. Soft-Start**: The FPS has an internal soft-start circuit that slowly increases the feedback voltage, together with the SenseFET current, right after it starts. The typical soft-start time is 15ms, as shown in Figure 19, where progressive increment of the SenseFET current is allowed during the startup phase. Soft-start circuit progressively increases current limits to establish proper working conditions for transformers, inductors, capacitors, and switching devices. It also helps to prevent transformer saturation and reduces the stress on the secondary diode.





**6. Burst Operation**: To minimize the power dissipation in standby mode, the FSQ100 enters burst-mode operation. As the load decreases, the feedback voltage decreases. The device automatically enters burst mode when the feedback voltage drops below  $V_{BURL}$  (0.55V). At this point, switching stops and the output voltages start to drop. This causes the feedback voltage to rise. Once is passes  $V_{BURH}$  (0.70V), switching starts again. The feedback voltage falls and the process repeats. Burst-mode operation alternately enables and disables switching of the power MOSFET to reduce the switching loss in standby mode.



# **Application Tips**

### 1. Methods of Reducing Audible Noise

Switching mode power converters have electronic and magnetic components that generate audible noise when the operating frequency is in the range of 20~20,000Hz. Even though they operate above 20kHz, they can make noise, depending on the load condition. Designers can employ several methods to reduce noise.

### **Glue or Varnish**

The most common method involves using glue or varnish to tighten magnetic components. The motion of core, bobbin and coil, and the chattering or magnetostriction of core can cause the transformer to produce audible noise. The use of rigid glue and varnish helps reduce the transformer noise, but can crack the core. This is because sudden changes in the ambient temperature cause the core and the glue to expand or shrink in a different ratio.

### **Ceramic Capacitor**

Using a film capacitor instead of a ceramic capacitor as a snubber capacitor is another noise-reduction solution. Some dielectric materials show a piezoelectric effect, depending on the electric field intensity. Hence, a snubber capacitor becomes one of the most significant sources of audible noise. It is possible to use a Zener clamp circuit instead of an RCD snubber for higher efficiency as and lower audible noise.

### **Adjusting Sound Frequency**

Moving the fundamental frequency of noise out of 2~4kHz range is the third method. Generally, humans are more sensitive to noise in the range of 2~4kHz. When the fundamental frequency of noise is located in this range, the noise is perceived as louder, although the noise intensity level is identical (refer to Figure 22 Equal Loudness Curves).

When FPS acts in burst mode and the burst operation is suspected to be a source of noise, this method may be helpful. If the frequency of burst-mode operation lies in the range of  $2\sim4$  kHz, adjusting the feedback loop can shift the burst operation frequency. To reduce the burst operation frequency, increase a feedback gain capacitor ( $C_F$ ), opto-coupler supply resistor ( $R_D$ ), and feedback capacitor ( $C_B$ ); and decrease a feedback gain resistor ( $R_F$ ), as shown in Figure 23.







Figure 23. Typical Feedback Network of FPS™

### 2. Reference Materials

<u>AN-4134 — Design Guidelines for Off-line Forward</u> <u>Converters using FPS™</u>

<u>AN-4137 — Design Guidelines for Off-line Flyback</u> Converters using FPS™

<u>AN-4138 — Design Considerations for Battery Charger</u> <u>Using Green Mode Fairchild Power Switch (FPS™)</u>

<u>AN-4140 — Transformer Design Consideration for Offline Flyback Converters Using Fairchild Power Switch</u> (FPS™)

<u>AN-4141 — Troubleshooting and Design Tips for</u> Fairchild Power Switch (FPS™) Flyback Applications

<u>AN-4147 — Design Guidelines for RCD Snubber of</u> <u>Flyback</u>

<u>AN-4148</u> — Audible Noise Reduction Techniques for <u>FPS™Applications</u>





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		Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.	
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